

$V_{DSS}$	20V
$R_{DS(on)}$ (Max.)	3.5Ω
$I_D$	100mA
$P_D$	150mW

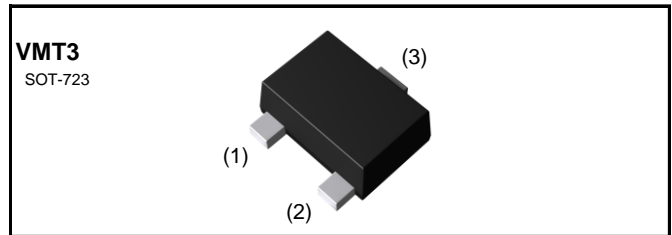
#### ●Features

- 1) Low voltage drive(1.2V) makes this device ideal for portable equipment.
- 2) Drive circuits can be simple.
- 3) Built-in G-S Protection Diode.

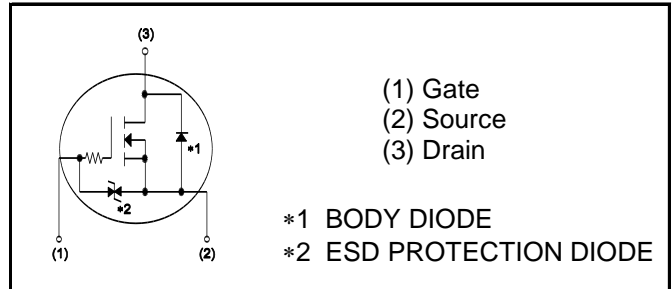
#### ●Application

Switching

#### ●Outline



#### ●Inner circuit



#### ●Packaging specifications

Type	Packaging	Taping
	Reel size (mm)	180
	Tape width (mm)	5.5
	Basic ordering unit (pcs)	8,000
	Taping code	T2L
	Marking	RW

#### ●Absolute maximum ratings( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Drain - Source voltage	$V_{DSS}$	20	V
Continuous drain current	$I_D^{*1}$	±100	mA
Pulsed drain current	$I_{D,pulse}^{*2}$	±400	mA
Gate - Source voltage	$V_{GSS}$	±8	V
Power dissipation	$P_D^{*3}$	150	mW
Junction temperature	$T_j$	150	°C
Range of storage temperature	$T_{stg}$	-55 to +150	°C

#### ●Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - ambient	$R_{thJA}^{*3}$	-	-	833	°C/W

●Electrical characteristics( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 1mA$	20	-	-	V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 20V, V_{GS} = 0V$	-	-	1	$\mu\text{A}$
Gate - Source leakage current	$I_{GSS}$	$V_{GS} = \pm 8V, V_{DS} = 0V$	-	-	$\pm 10$	$\mu\text{A}$
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_D = 100\mu\text{A}$	0.3	-	1.0	V
Static drain - source on - state resistance	$R_{DS(on)}$ *4	$V_{GS}=4.5V, I_D=100mA$	-	2.5	3.5	$\Omega$
		$V_{GS}=2.5V, I_D=100mA$	-	3.0	4.2	
		$V_{GS}=1.8V, I_D=50mA$	-	3.8	5.3	
		$V_{GS}=1.5V, I_D=20mA$	-	4.5	9.0	
		$V_{GS}=1.2V, I_D=10mA$	-	6.0	18.0	
		$V_{GS}=4.5V, I_D=100mA, T_j=125^\circ\text{C}$	-	4.0	5.6	
Transconductance	$g_{fs}$ *4	$V_{DS}=10V, I_D=100mA$	180	-	-	mS

\*1 Limited only by maximum temperature allowed.

\*2  $P_w \leq 10\mu\text{s}$ , Duty cycle  $\leq 1\%$

\*3 Each terminal mounted on a recommended land

\*4 Pulsed

**●Electrical characteristics**( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	$C_{iss}$	$V_{GS} = 0\text{V}$	-	7.1	-	pF
Output capacitance	$C_{oss}$	$V_{DS} = 10\text{V}$	-	3.3	-	
Reverse transfer capacitance	$C_{rss}$	$f = 1\text{MHz}$	-	1.7	-	
Turn - on delay time	$t_{d(on)}^{*4}$	$V_{DD} \approx 10\text{V}, V_{GS} = 4.5\text{V}$	-	5	-	ns
Rise time	$t_r^{*4}$	$I_D = 50\text{mA}$	-	4	-	
Turn - off delay time	$t_{d(off)}^{*4}$	$R_L = 200\Omega$	-	20	-	
Fall time	$t_f^{*4}$	$R_G = 10\Omega$	-	38	-	

**●Body diode electrical characteristics** (Source-Drain)( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Continuous source current	$I_S^{*1}$	$T_c = 25^\circ\text{C}$	-	-	100	mA
Pulsed source current	$I_{SM}^{*2}$		-	-	400	mA
Forward voltage	$V_{SD}^{*4}$	$V_{GS} = 0\text{V}, I_S = 100\text{mA}$	-	-	1.2	V

●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

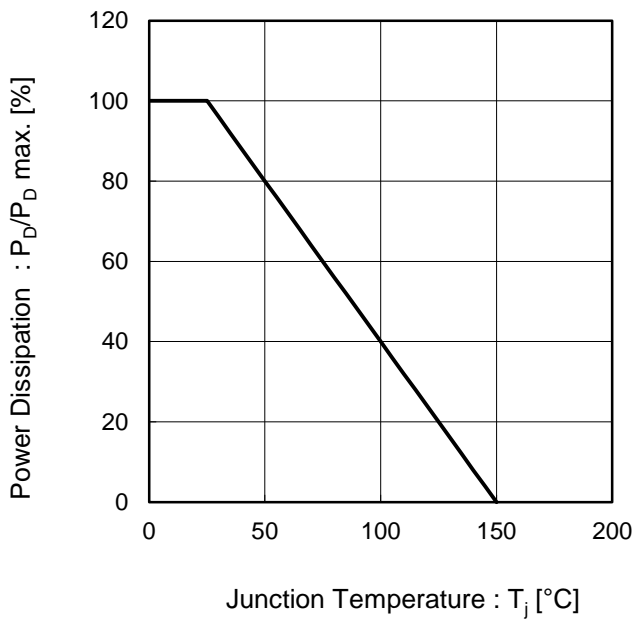


Fig.2 Drain Current Derating Curve

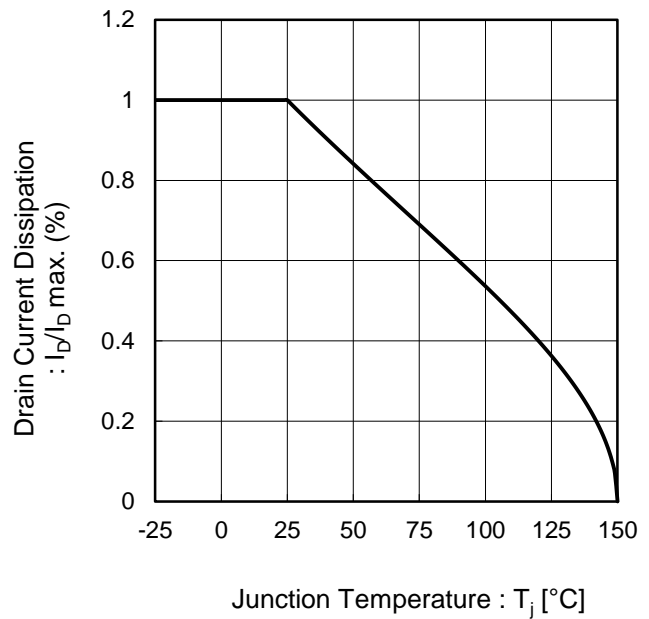


Fig.3 Typical Output Characteristics(I)

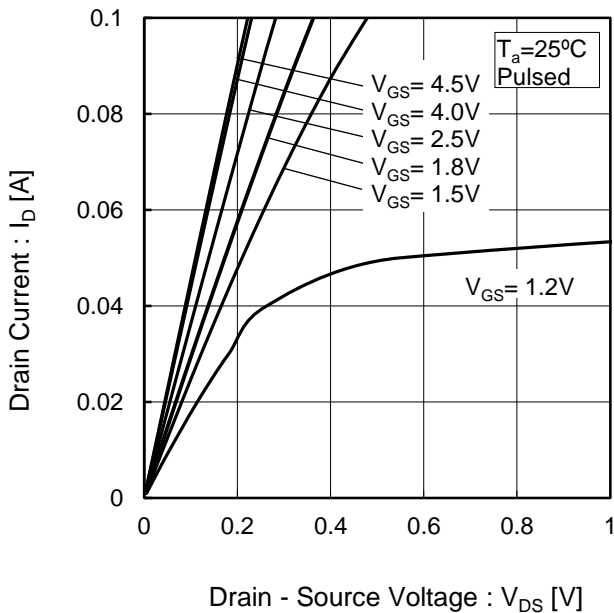
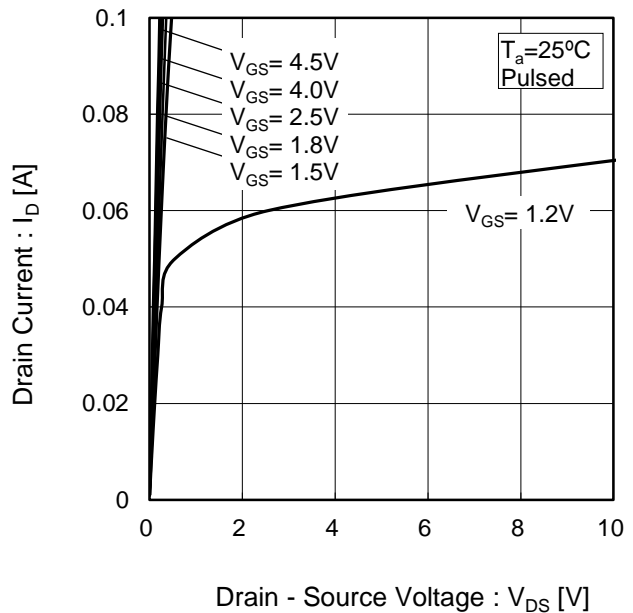


Fig.4 Typical Output Characteristics(II)



●Electrical characteristic curves

Fig.5 Breakdown Voltage vs. Junction Temperature

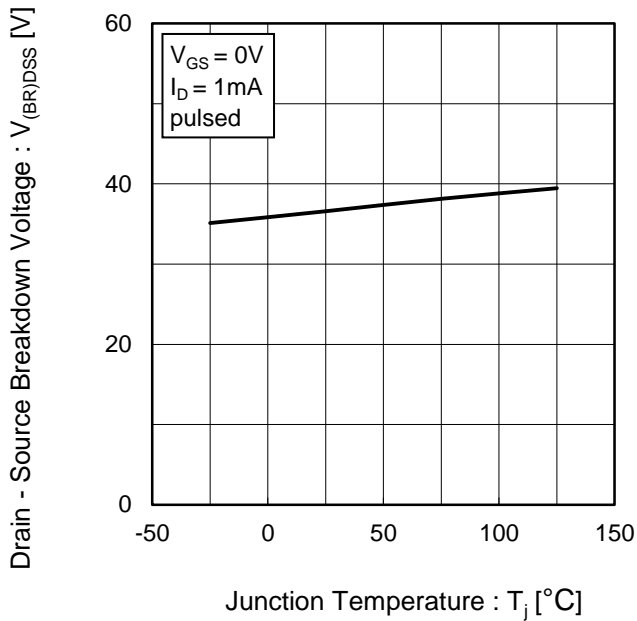


Fig.6 Typical Transfer Characteristics

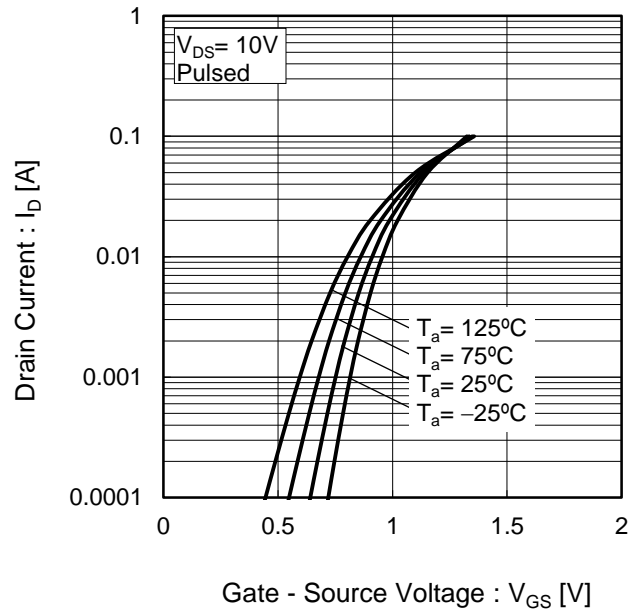


Fig.7 Gate Threshold Voltage vs. Junction Temperature

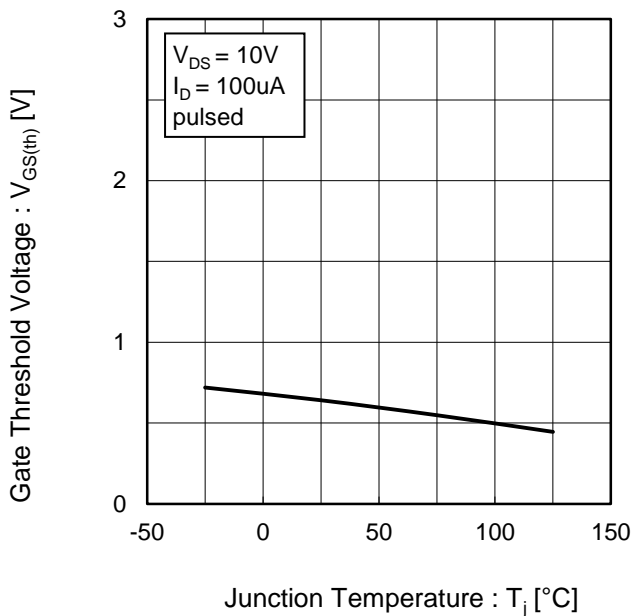
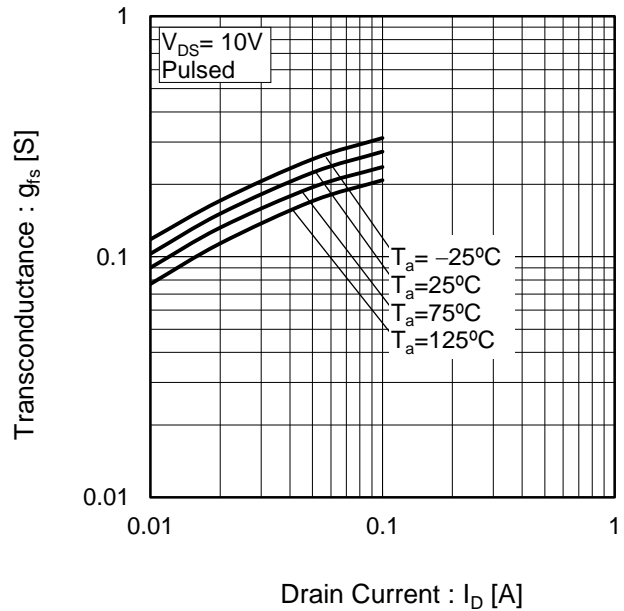


Fig.8 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.9 Static Drain - Source On - State Resistance vs. Gate Source Voltage

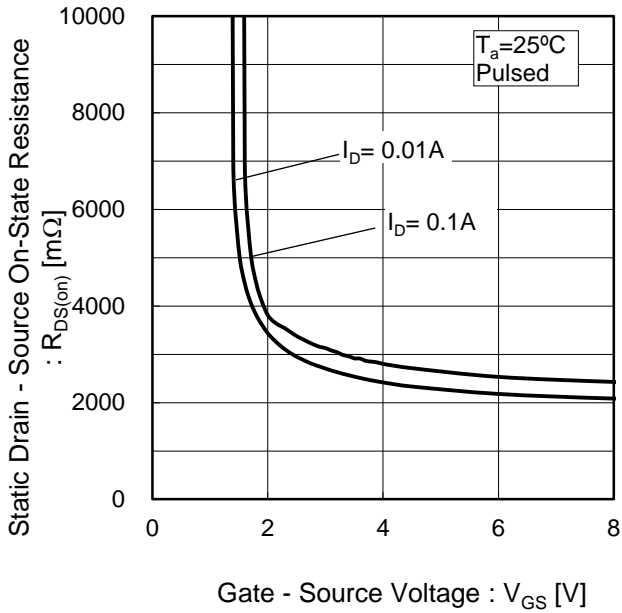


Fig.10 Static Drain - Source On - State Resistance vs. Drain Current(I)

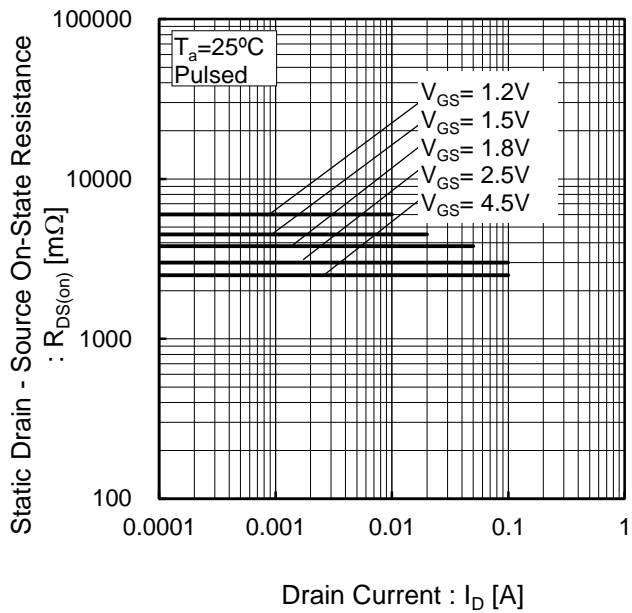


Fig.11 Static Drain - Source On - State Resistance vs. Junction Temperature

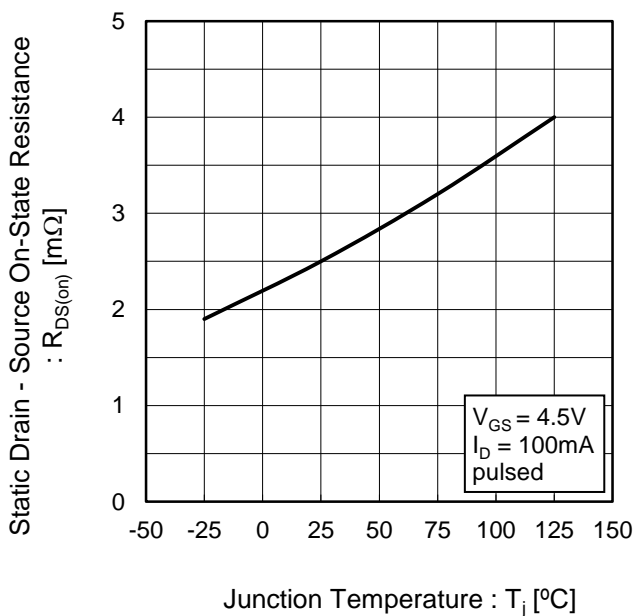
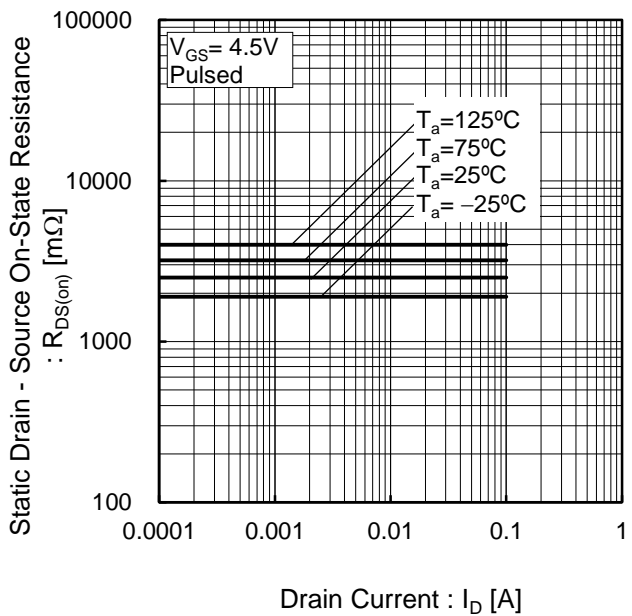


Fig.12 Static Drain - Source On - State Resistance vs. Drain Current(II)



●Electrical characteristic curves

Fig.13 Static Drain-Source On-State Resistance vs. Drain Current(III)

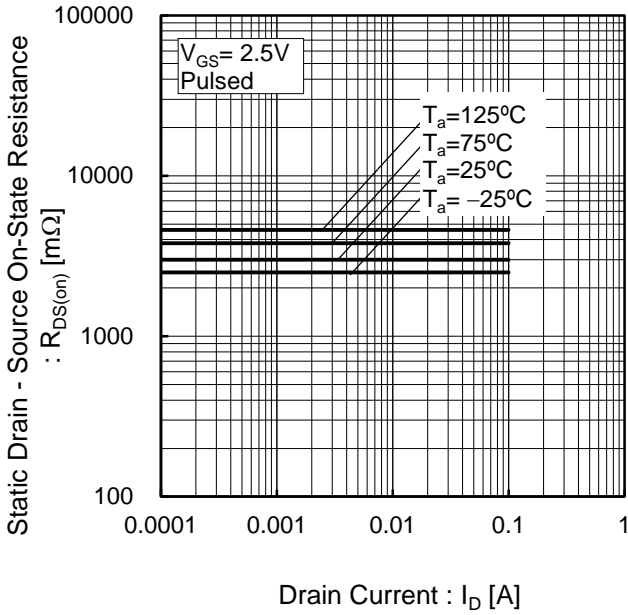


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(IV)

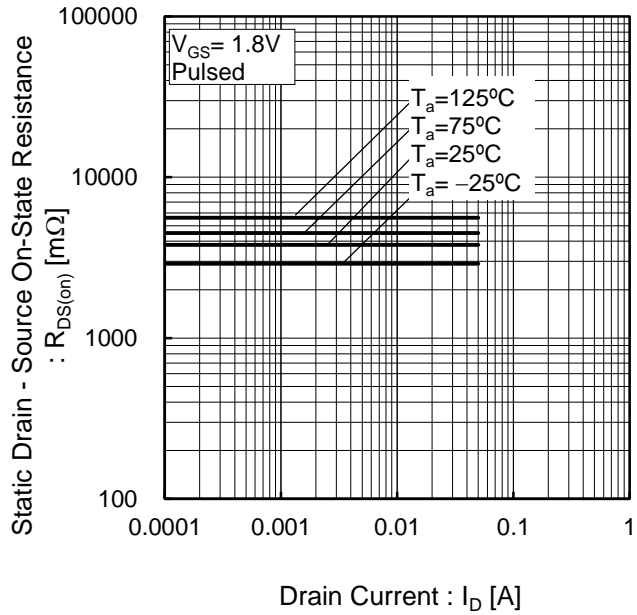


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(V)

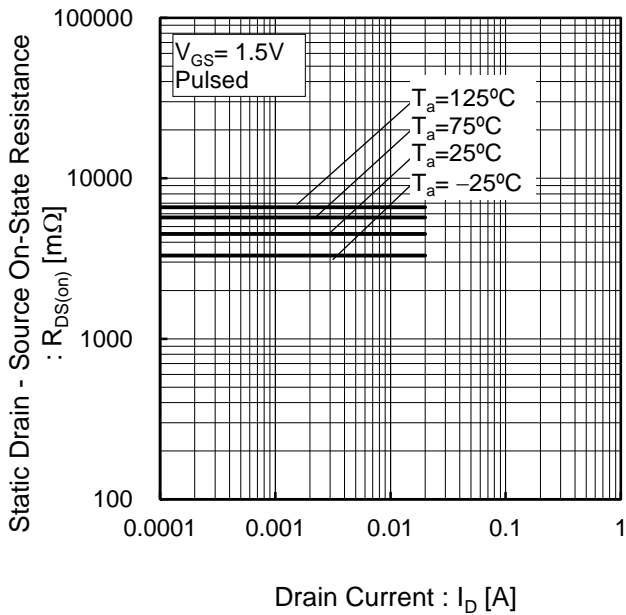
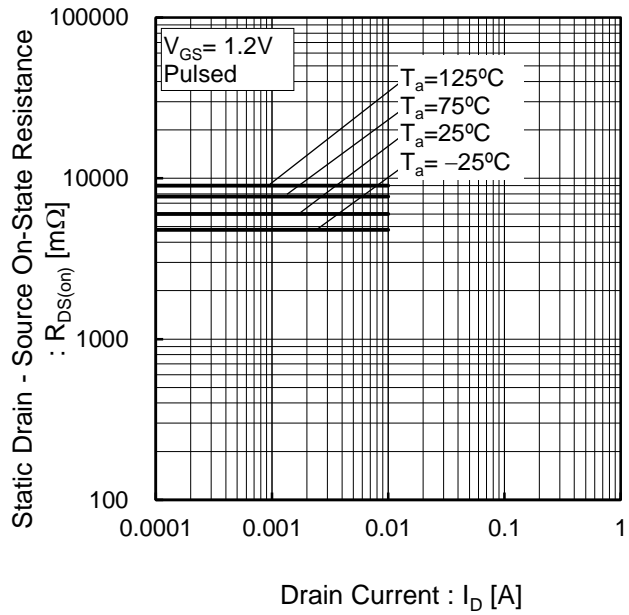


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(VI)



●Electrical characteristic curves

Fig.17 Typical Capacitance vs. Drain - Source Voltage

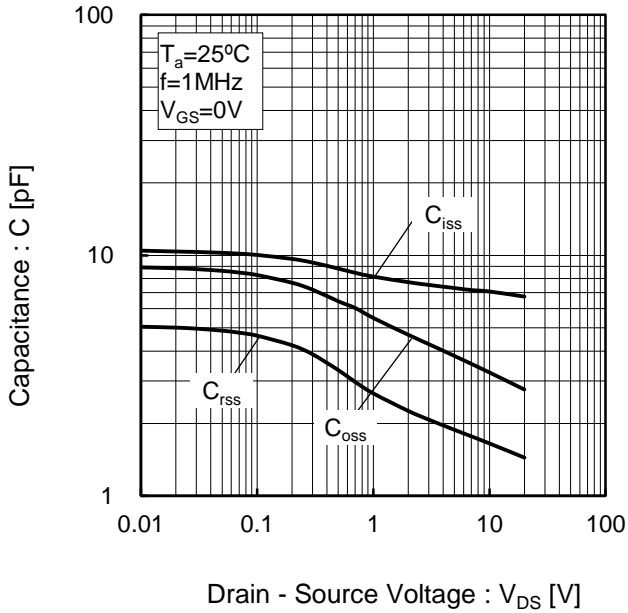


Fig.18 Switching Characteristics

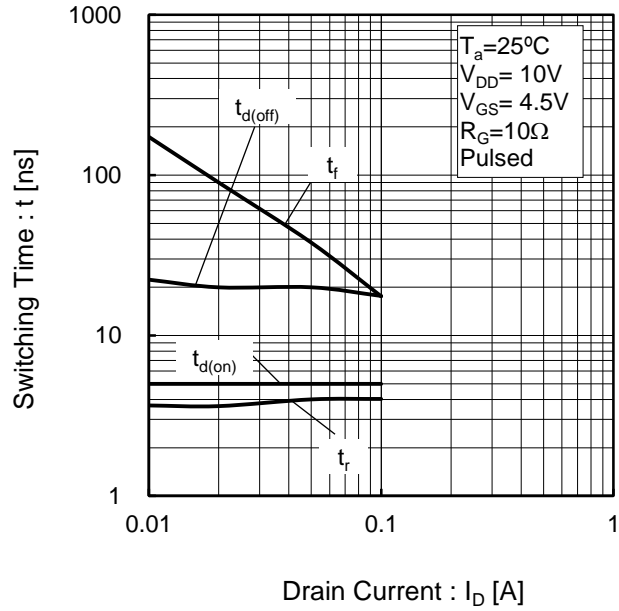
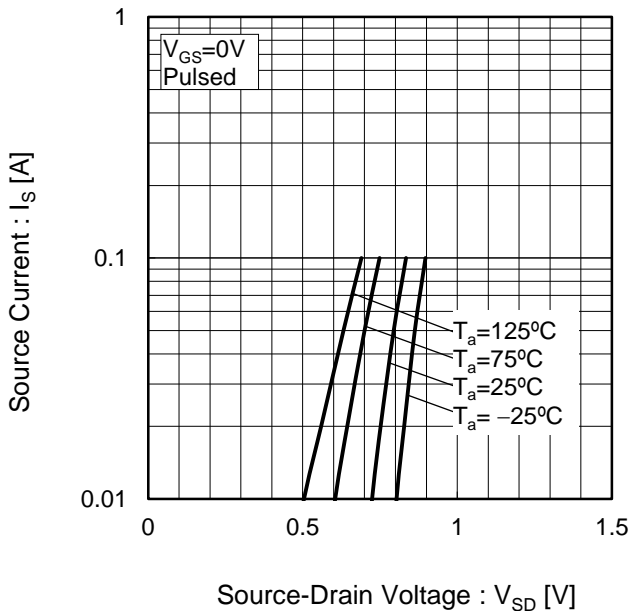


Fig.19 Source Current vs. Source Drain Voltage





### ●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

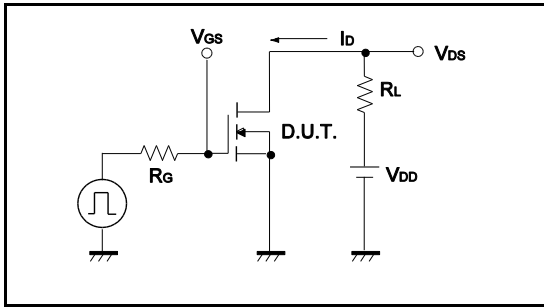
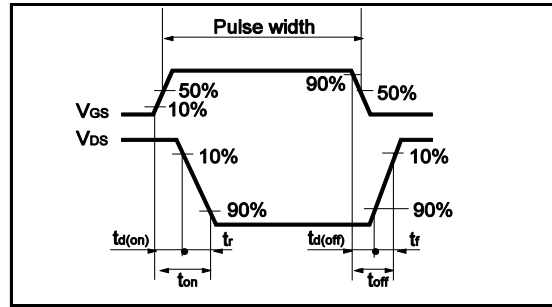


Fig.1-2 Switching Waveforms



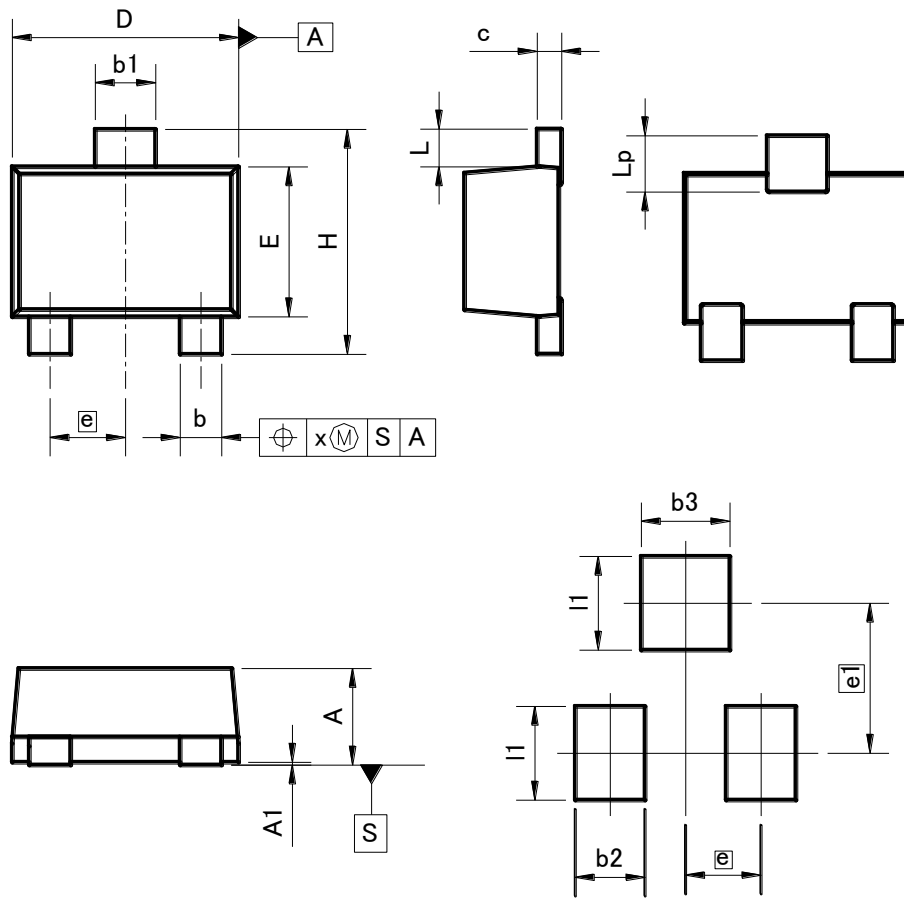
### ●Notice

This product might cause chip aging and breakdown under the large electrified environment.

Please consider to design ESD protection circuit.

●Dimensions (Unit : mm)

VMT3



Pattern of terminal position areas

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0	0.004
b	0.17	0.27	0.007	0.011
b1	0.27	0.37	0.011	0.015
c	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
e	0.40		0.02	
HE	1.10	1.30	0.043	0.051
L	0.10	0.30	0.004	-
Lp	0.20	0.40	0.008	-
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	0.80		0.03	
b2	-	0.37	-	0.015
b3	-	0.47	-	0.019
l1	-	0.50	-	0.02

Dimension in mm/inches

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